

Circular economy of ITO thin films deposited on glass obtained from degraded OLED devices

Economia circular de filmes finos de ITO depositados sobre vidro obtidos de dispositivos OLEDs degradados

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Section Editor: Maria Lúcia Pereira da Silva

Received: 10 Jun 2021 Approved: 20 Jul 2021

ABSTRACT

In this work, circular economy was investigated for commercial indium tin oxide (ITO) thin films deposited on glass substrates obtained from degraded organic light-emitting diodes (OLED). These devices were assembled and polarized at laboratory in a previous work. For each substrate, with geometry 2.5 × 2.5 cm, four OLEDs with active area of 3 × 3 mm were set up. These OLED devices were assembled with ITO as the electrode anode and successive depositions of other materials (layer-by-layer), to form the complete structure. To obtain the recovered ITO, all layers were removed from the samples containing the OLEDs previously mounted, remaining only the ITO thin films, that were cleaned with commercial product together with the received ITO/glass samples. Both samples were compared using some techniques, such as: colorimetry, electrical resistance, and Raman spectroscopy. A methodology with light-emitting diode (LED) device polarized emitting light crossing the ITO thin films was used, and the luminance with chromaticity coordinates was obtained, revealing the good transparency of the thin films. Electrical resistance of recovered ITO revealed five higher orders of magnitude in comparison to the one of received ITO. This fact can be tributed to a poly(3,4-ethylenedioxythiophene) doped with poly(styrenesulfonate) (PEDOT:PSS) layer, causing corrosion of the ITO thin films during the assembly of OLEDs or loss of the field lines created during the electrical measurements by probes of four-point probe. Raman spectroscopy did not show satisfactory results in the chemical composition analyses of the samples, but it indicated good cleaning process of the samples before the analyses.

KEYWORDS: ITO, OLED, Circular economy, Colorimeter, Electrical resistance, Raman spectroscopy.

RESUMO

Neste trabalho, a economia circular foi investigada para filmes finos de óxido de índio e estanho (ITO) comerciais depositados sobre substratos de vidro obtidos de diodos orgânicos emissores de luz (OLEDs) degradados. Esses dispositivos foram montados e polarizados em outro trabalho. Sobre cada lâmina, com geometria de 2,5 × 2,5 cm, foram montados quatro OLEDs com geometria de área ativa de 3 × 3 mm. Esses dispositivos OLEDs foram montados com eletrodo anodo de ITO e sucessivas deposições de outros materiais (camada por camada), para formar a estrutura completa. Para obter o ITO recuperado, todas as camadas foram removidas de todas as amostras contendo os OLEDs anteriormente montados, restando apenas os filmes finos de ITO, que foram limpos com produto comercial juntamente com outras amostras de ITO/vidro recebidas pelo mesmo fabricante. Ambas as amostras foram comparadas usando algumas técnicas, tais como: colorimetria, resistência elétrica e espectroscopia Raman. Uma metodologia com



dispositivo LED polarizado emitindo luz atravessando os filmes finos de ITO foi utilizada, e a luminância com coordenadas de cromaticidade foi obtida, revelando boa transparência dos filmes. Medida de resistência elétrica do ITO recuperado revelou cinco ordens de grandezas maiores em comparação com as do ITO recebido. Esse fato pode ser atribuído pela camada de PEDOT:PSS, causando a corrosão dos filmes finos de ITO durante a montagem dos dispositivos OLEDs ou perda de linhas de campo criadas durante as medidas de resistência elétrica pelas pontas de prova de quatro pontas. Espectroscopia Raman não mostrou resultados satisfatórios nas análises de composição química das amostras, mas revelou bom processo de limpeza das amostras, que foi realizada antes das análises.

PALAVRAS-CHAVE: ITO, OLED, Economia circular, Colorímetro, Resistência elétrica, Espectroscopia Raman.

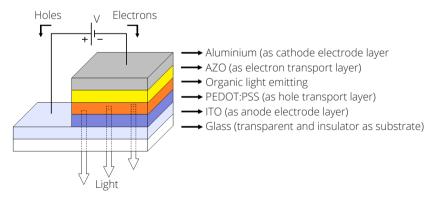
INTRODUCTION

Organic light-emitting diodes (OLEDs) can be characterized as electroluminescent semiconductor devices that uses multilayer structures of organic materials^{1,2}. The organic multilayer is inserted between an anode used as a transparent conductive oxide (TCO) and a cathode used as a metallic thin film^{3,4}. OLED devices were presented in 1987 by two researchers of Eastman Kodak Company known as Ching Wang Tang and Steven Van Slyke⁵. They announced the creation of an OLED device involving organic materials with multilayer structure such as glass/indium tin oxide (ITO)/diamine/8-tris-hydroxyquinoline aluminum (Alq3)/magnesium (Mg): silver (Ag)⁵.

Some years later, the advances of this technology allowed to obtain better efficiency and purity of organic materials with considerable improvement of the performance of OLEDs. Nowadays, these devices are used for some applications, such as: smart televisions, smartphones, smartwatches, luminaires and in automotive area^{6,7}. OLEDs have allured the interest of some companies because they have been used as displays substituting the traditional liquid crystal displays (LCDs) with superior advantages, such as: highest brightness, wide view angle (~170°), color reproduction fidelity, high sharpness and low response time^{8,9}. The OLED application in displays with flexible substrates for consumer products has been released by some companies as: Samsung, LG, Motorola and Huawei¹⁰⁻¹².

Structure and materials of OLED devices

In literature, there are multilayer structures for assembling OLED devices with a variable number of thin films, but the structure that has been studied presenting satisfactory results in low voltage and illuminance terms use five layers at least, as showed in Fig. 1^{13,14}.



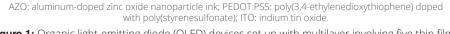


Figure 1: Organic light-emitting diode (OLED) devices set up with multilayer involving five thin films.

Rigidness, transparency and electrical insulator are required properties of the glass used as a substrate of OLEDs. Glass also contributes to avoid the diffusion of oxygen and moisture from ambient, both significantly

leading to degradation of OLED devices¹⁵. The transparent conductive oxide (TCO) thin film is deposited on the glass substrate. TCO is a type of semiconductor that offers: high optical transparency (\approx 90%) to light crossing, good electrical conductivity (from \approx 7.10⁻⁵ to 5.10⁻⁴ Ω .cm), sheet resistance (from 5 to 15 Ω/\Box) and workfunction between 4.5 to 5.3 eV. This material is used as an electrode anode, promoting the injection of hole charge carriers inside the OLED¹⁶.

Successive layers with different functions are deposited on the TCO, such as organic hole transport layer (HTL), to better locomotion of the holes charges; organic active material, to light generation; and organic electron transport layer (ETL), to better locomotion of the electrons charges. On the top of the structure, metal layer is deposited, which is the electrode anode that promotes the electron injection inside the OLED device¹⁷. To improve the lifetime, threshold voltage and electrical current level are preserved the same, and illuminance is suggested as the encapsulation of the devices^{18,19}.

Transparent conductive oxide

As TCO thin film, ITO has been very used as electrode anode in OLED devices and other ones, such as: organic solar cells (OPVs), LCDs, smart windows, photothermic converters and gas sensors²⁰. The ITO thin film has expansive cost, due to indium, that is a rare chemical element found in nature. For this motive, it compromises \approx 40% the cost of the OLED devices. ITO thin films are not produced in Brazil, but there are several companies around the world that manufacture them (United States, Japan, England, Hong Kong, South Korea, Taiwan, and China). Table 1 shows the comparison between different manufacturers of ITO thin films deposited on glass as substrates with price, geometry (length × width × thickness), sheet resistance and transmittance for 25 substrates (package with minimum number available).

Supplier	Code	Sheet resistance	Transmittance	Geometry	Price
		(Ω/□)	(%)	(mm)	(US\$)
Sigma-Aldrich	578274-25PAK	8-12	>83%	75 × 25 × 1.1	2,253
Diamond Coatings	SL-P-12 OLED	15	~86%	355 × 406 × 1.1	918
Techinstro	TIX005	10	>85%	100 × 100 × 0.7	707

Table 1: Different suppliers of indium tin oxide (ITO) deposited on glass substrates.

Pure indium (In) oxide without doping of tin (Sn) is considered a material with electrical insulator property, but, when it is modified with oxygen vacancies, there is the possibility to reach high levels of n type (negative material), due its intrinsic defects²¹. When doped with Sn, this material becomes an impurity donor, because it is a tetravalent element (Sn) doped with a trivalent chemical element (In)²². Then, two mechanisms are possible to occur to generate electrical conduction in ITO thin films, such as:

- Carried out by oxygen vacancies in the In oxide structure, donating up to two free electrons to form the In_2O_{3-x} structures^{23,24};
- \cdot Carried out by random substituting of In^{3+} ions to Sn^{4+} , donating one electron to the electrical conduction layer^{25,26}.

After these two mechanisms, the ITO increases its carrier concentration, respectively, from 10¹³ to 10¹⁷ cm⁻³ and from 10¹⁹ to 10²¹ cm⁻³ ^{22,23,27}, a characteristic of semiconductor materials. Although the tin doping improves the electrical characteristic of ITO, there is a limit value that can be used in the material, because there is reduction of Hall mobility, and it considerably causes the decrease of transmittance. Studies report that the best proportion is 10 mol% of tin and 90 mol% of In oxide^{22,23}. Another factor that interferes on the optical and electrical characteristics of ITO is the technique used to fabricate the thin films and also to process the parameters (including the chamber geometry and accessories) used during the deposition. The electrical, optical, and chemical characterization of the ITO thin films can be used:

· Scanning electron microscopy with energy dispersion scattering, to identify the morphology and chemical composition;

Atomic force microscopy, to verify the surface roughness;

- · Ultraviolet-visible spectrophotometer, to obtain the transmittance or absorbance;
- · Hall effect, to investigate the carrier concentration, Hall mobility and electrical resistance;
- Four-point probe, to analyze the sheet resistance;
- · Contact angle, to verify the scattering of materials on the surface;
- · Ellipsometry, used to identify the doping concentration;
- Profilometer, to obtain the thickness;
- Kelvin probe, ultraviolet photoelectron spectroscopy or x-ray photoelectron spectroscopy, to identify the workfunction of ITO thin films.

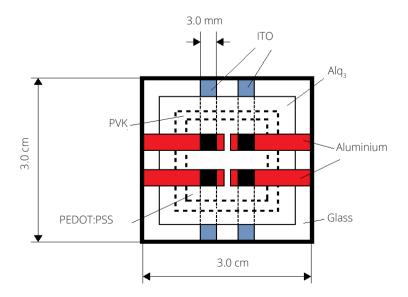
The importance of ITO recycling

Since ITO is present in devices of general applications, it is responsible for high economic, scientific-technological and social impact, because the production of this material influences the quality of human life²³. Then, the circular economy of this material is fundamental, contributing to the decrease of the production cost of TCOs and also of the waste produced worldwide. Nowadays, the recycling method is responsible for 60% of the In produced around the world, where the main material is the ITO present in LCDs²⁵. Many countries have carried out ITO recycling, such as: China, Japan and South Korea²⁵.

Differently of what happen in these countries, consumer electronic products in Brazil used by people and devices used at research laboratories are sent to landfills, and this attitude has been a significant economic waste. Another problem found in Brazil is related to the expansive cost of ITO/glass, because there is no company to produce this material. Then, to minimize these problems, in this work, the circular economy concept is explored showing a technique to recuperate ITO/glass thin films extracted of degraded OLEDs that were set up and tested at laboratory in a previous work²⁸. This material recovered was compared to new substrates (as received) of the same manufacturer/supplier, using optical, electrical, and chemical characterization.

MATERIALS AND METHODS

The ITO thin films deposited on glass substrates were extracted from degraded OLEDs and studied in another work. The multilayer structure of OLED obtained used the materials: glass/ITO/poly(3,4-ethylenedioxythiophene) doped with poly(styrenesulfonate) (PEDOT:PSS) /poly(N-vinylcarbazole) (PVK)/8-tris-hydroxyquinoline aluminum (Alq³)/Al²⁸. Figure 2 shows the materials and geometry of the substrate containing four set-up OLED devices.



ITO: indium tin oxide; PVK: poly(N-vinylcarbazole); PEDOT:PSS: poly(3,4-ethylenedioxythiophene) doped with poly(styrenesulfonate). **Figure 2:** Materials and geometry of the substrates containing four OLED devices²⁸.

On each substrate, four OLED were set up at the same time. Each device presented anode and cathode (only the deposition of organic layers was common for the four devices) inside the glove box system, under nitrogen atmosphere and relative humidity of 20%²⁹. These degraded OLED devices used commercial ITO/glass substrates supplied from DisplayTech company. The samples with ITO/glass recovered were compared to the received samples (new substrates) from the company.

To remove the multilayers of the degraded OLED devices, a five-step process was used:

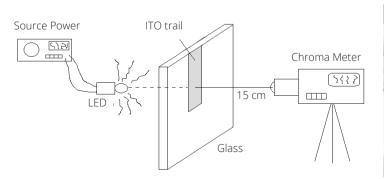
- Step 1: inside the Becker glass, the samples with degraded OLED were immersed into the alcohol solution, then the Becker was sealed with plastic film (to avoid the evaporation of alcohol) for three days;
- Step 2: cotton and acetone were used for each sample scrubbing to complete remotion of the multilayers (avoiding damaging the ITO thin trails);
- Step 3: inside the Becker, the samples were immersed into acetone, and the Becker was sealed with plastic film (to avoid the evaporation of acetone) for eight days to remove possible residues;
- Step 4: inside the Becker, the samples were immersed into the current water for six days;
- Step 5: to remove any remnants cotton scrubbing with a domestic abrasive cleaning product was used on the surface of the substrates, including the ITO trails.

This cleaning method was suggested and selected for this investigation, because it causes no changes (decrease of the thickness, for example) in the property of the ITO thin films.

After recuperation of ITO thin films, all samples (including the received ones) were cleaned by a process to remove possible particles, dust, and grease, using rubber gloves, common detergent and current water scrubbing the surfaces. Then, a product commercialized in Brazilian market called Aqua Brilho Restaurador de Superfície was used, putting some drops and scrubbing with cotton until the complete evaporation of the solvent (water), finishing the cleaning method³⁰.

Characterization of commercial ITO/glass

Optical characteristics of ITO thin films were analyzed using a chroma meter manufactured by Konica Minolta, model CS-200, to obtain luminance (cd/m²) and chromaticity coordinates (x and y). In this technique, a LED with white emission was polarized at 2.50 V and 0.032 mA using a source power manufactured by Keithley, 2400 series. In this analysis methodology, the ITO trail was placed between LED and chroma meter with 15-cm of distance. Figure 3 shows the arrangement of the experiment used. The analyses were carried out at a laboratory with a turned-off ambient illumination (to avoid possible interferences in the measurements). The LED was measured (without interference of the ITO thin film) as reference. To the ITO recovered, four measurements were obtained, and to the received ones three measurements were obtained.





LED: light-emitting diode; ITO: indium tin oxide. **Figure 3:** Arrangement using chroma meter, LED and ITO thin film.

Electrical characteristic of ITO thin films was analyzed using a digital multimeter manufactured by Tektronix, model DMM 4020, connected to an analogic four-point probe manufactured by A&M Fell, model B. The probe cords (positive and negative) of digital multimeter were connected to the electrical connectors of four-point

probe, and the sample was positioned on the center of the horizontal support of the equipment. Measurements were manually initialized moving the crowbar to turn down containing the two probes up to touch the surface of ITO thin film.

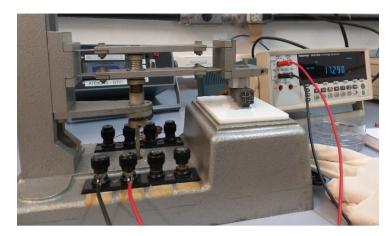


Figure 4: Analogic four-point probe connected by multimeter to analyze electrical resistance.

Chemical characteristic of ITO thin films was analyzed by Raman spectroscopy to investigate the chemical composes on the surface. The equipment used was manufactured by Witec, Confocal Raman microscope, model Alpha 300 R, that uses green laser and objective lens with magnification level of 50x. In this technique, inelastic monochromatic light spreads on the molecules.

RESULTS

Analyses with chroma meter

Analyses of LED

Five analyses with chroma meter revealed good precision on luminance, and the chromaticity coordinates (x and y) results showed good stability of the light emission for the experiments using LED. Luminance measurements revealed little variation that only can be caused by oscillations of the energy line (power supply connected to 110 volts) or frequency used with power line of 60 Hz (turned-on and turned-off). For this motive, both electrical characteristics might have affected the sensibility of chroma meter. Table 2 shows the luminance and chromaticity coordinates (x and y) of LED with white emission polarized at 2.5 V and 0.032 mA.

LED	Luminance	Chromaticity coordinates		
LED	(cd/m²)	x	У	
	2,677	0.2658	0.2663	
	2,678	0.2658	0.2663	
Polarized at 2.50 V e 0.032 mA	2,679	0.2658	0.2663	
	2,680	0.2658	0.2663	
	2,679	0.2658	0.2664	
Average ± standard deviation	2,679 ± 1	0.2658 ± 0.0000	0.2663 ± 0.0000	

Analyses of ITO/glass thin films

Both received and recovered ITO/glass substrates were placed in front of the polarized LED at the same conditions using only the LED. Five analyses with chroma meter revealed good precision on results obtained by luminance and chromaticity coordinates x and y (with four decimal numbers), and good stability of the light emission for only LED. For received ITO/glass, the illuminance and chromaticity coordinates measurements were carried out at three different regions (a, b and c) on the same received sample.

The values in Table 3 reveal good uniformity of thin films with luminance value of 2,484 \pm 15 cd/m² and low standard deviation for the same received sample.

 Table 3: Received sample: luminance and chromaticity coordinates for indium tin oxide (ITO) as received/glass/light-emitting diode (LED) measured at different regions (a, b and c).

Decisy	Luminance	Chromaticity coordinates		
Region	(cd/m²)	x	у	
	2,500	0.2667	0.2746	
_	2,500	0.2667	0.2746	
a	2,501	0.2666	0.2745	
_	2,502	0.2666	0.2746	
_	2,500	0.2667	0.2745	
Average ± standard deviation	2,501 ± 1	0.2666 ± 0.0001	0.2746 ± 0.0001	
	2,467	0.2648	0.2707	
_	2,465	0.2648	0.2706	
b	2,467	0.2648	0.2707	
_	2,467	0.2648	0.2707	
_	2,466	0.2648	0.2707	
Average ± standard deviation	2,467 ± 1	0.2648 ± 0.0000	0.2707 ± 0.0001	
	2,485	0.2676	0.2759	
_	2,482	0.2676	0.2759	
C	2,485	0.2675	0.2759	
_	2,486	0.2675	0.2759	
_	2,485	0.2675	0.2759	
Average ± standard deviation	2,485 ± 2	0.2675 ± 0.0001	0.2759 ± 0.0000	

The luminance and chromaticity coordinates (x and y) measurements for ITO/glass recovered were obtained at the same regions of active areas (4 × 4 mm) from OLEDs (with four devices obtained at the same substrate) previously assembled and tested. These regions were named as R1, R2, R3 and R4. In comparison of received and recovered ITO/glass, insignificant differences were verified, suggesting that the recovered ITO/glass had some changes in its optical characteristic (transmittance, for example) caused by multilayers structure of OLED.

Table 4: Recovered sample: luminance and chromaticity coordinates for indium tin oxide (ITO) recovered/glass/light-emitting diode (LED) measured at different regions (R1, R2, R3 and R4).

Degion	Luminance	Chromaticity coordinates		
Region	(cd/m²)	x	У	
	2,466	0.2639	0.2686	
_	2,467	0.2640	0.2686	
R1	2,468	0.2640	0.2686	
_	2,469	0.2639	0.2686	
_	2,471	0.2640	0.2686	
Average ± standard deviation	2,468 ± 2	0.2640 ± 0.0001	0.2686 ± 0.0000	
	2,471	0.2644	0.2684	
_	2,473	0.2644	0.2684	
R2	2,475	0.2644	0.2684	
_	2,478	0.2644	0.2685	
_	2,478	0.2644	0.2684	
Average ± standard deviation	2,475 ± 3	0.2644 ± 0.0000	0.2684 ± 0.0001	
	2,461	0.2657	0.2706	
	2,463	0.2657	0.2706	
R3	2,464	0.2656	0.2705	
_	2,465	0.2656	0.2704	
_	2,466	0.2656	0.2704	
Average ± standard deviation	2,464 ± 2	0.2656 ± 0.0001	0.2705 ± 0.0001	
	2,492	0.2653	0.2704	
_	2,490	0.2653	0.2704	
R4	2,488	0.2652	0.2703	
_	2,488	0.2652	0.2703	
_	2,487	0.2652	0.2703	
Average ± standard deviation	2,489 ± 2	0.2652 ± 0.0001	0.2703 ± 0.0001	

Analyses of Raman spectroscopy

The chemical analyses to common glass, received ITO and recovered ITO were carried out by Raman spectroscopy. As reference measurement, first, the analysis of previous-cleaned common glass manufactured by Precision Glass Line company was obtained. Figure 5 shows the results of Raman spectroscopy to the common

glass with wavenumber of \approx 1,100 cm⁻¹, that is related by relative peak of the asymmetric chemical bond Si-O-Si. The wavenumber from 2,850 to 2,900 cm⁻¹ is related to the chemical bond of carbon with hydrogen.

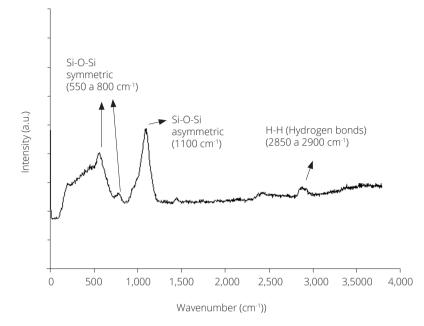


Figure 5: Raman spectroscopy of common glass substrate (without indium tin oxide thin film) used as reference.

In Fig. 6, received ITO thin film shows similar aspects compared with glass (Fig. 5), but it was found a peak shift of C-H from 2,850 to 2,900 cm⁻¹ to the lowest wavelength, from 2,380 to 2,500 cm⁻¹.

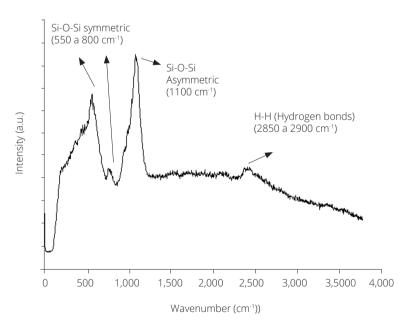


Figure 6: Raman spectroscopy of indium tin oxide (ITO)/received glass.

In comparison between ITO/received glass (Fig. 6) and ITO/recovered glass (Fig. 7), a similar behavior was verified, and new compounds adsorbed on the surface were not found.

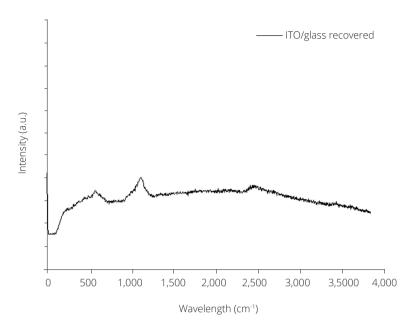


Figure 7: Raman spectroscopy of indium tin oxide (ITO)/recovered glass.

Analyses of electrical resistance with four-point probe

Table 5 presents the results of electrical resistance to ITO/received glass and ITO/recovered glass, showing a significant difference as high electrical resistance involving five orders of magnitude between both conditions.

ITO/received glass (Ω.10)	ITO/recovered glass (Ω.10⁵)		
82	3.40		
55	3		
74	5.80		
76	4		
94	5.40		
Average ± standard deviation			
75 ± 14	4.18 ± 1.23		

 Table 5: Electrical resistance measurements of indium tin oxide (ITO)/received glass and ITO/recovered glass.

The hypothesis for this discrepant result found in Table 5 can be explained because of ITO/recovered glass was corroded by PEDOT:PSS layer, that is the first material deposited during the assembly of OLED devices. In this case, this HTL presented acidity (pH of 1.5-2.5 and 25°C to dried coatings), causing chemical attack on the surface of ITO thin films. In turn, the original thickness of ITO (656 nm) decreased, and consequently the electrical resistance and sheet resistance increased considerably^{28,31,32}. If this ITO manufactured by DisplayTech company decreased in thickness for some reason, it can be still used as an anode electrode for assembly new OLED devices, since its original thickness is very elevated in comparison to other suppliers, as reported in Fullenbach²⁸. For example, Fullenbach²⁸ found a thickness variation from 16 to 83% related to different suppliers.

Figure 8 shows the chemical attack (spots) caused by three PEDOT:PSS droplets placed on the surface of ITO thin films that were left by some days and removed causing visual changes on the original color of TCO. There is a possibility that these significant changes cause variations of the thickness.

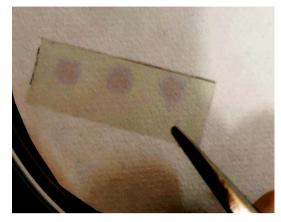


Figure 8: Three spots caused by acidity of poly(3,4-ethylenedioxythiophene) (PEDOT:PSS) on indium tin oxide (ITO) thin film.

Another hypothesis related to the difference of the electrical resistance values for both ITOs can be related to the thin trails of ITO/recovered glass used as electrical pads. In this case, during the electrical resistance measurements by four-point probe, discontinuity of the electrical field lines may have occurred, promoted by probes, and consequently increases of the electrical resistance. This condition of measurements used to thin trails of the recovered ITO films presented limitation of the method proposed. For this motive, the result obtained was not very conclusive. This fact did not occur with ITO/received glass, because the superficial area of ITO was much higher than the distance between the two probes used, presenting less than 1 mm.

CONCLUSION

Commercial ITO thin films deposited on glass substrates were obtained from degraded OLED devices and compared with received ones from suppliers. Both materials were investigated through optical, chemical, and electrical characterizations. The recovered ITO/glass thin films presented insignificant variations on the optical results, as luminance and chromaticity coordinates, when it was compared with received samples.

The electrical analyses of recovered ITO/glass showed high electrical resistances, that can be related to thin trails (used during the OLEDs set up). Because of that, there was loss in electrical field lines of probes used during the analyses. Another motive for the found high electrical resistance values can be related to partial corrosion of the thin film caused by ITO chemical attack, due to the acidity of PEDOT:PSS layer, that is the first material deposited on ITO during the OLED devices assemblance. In turn, thickness measurements of recovered ITO are suggested.

The analyses of Raman spectroscopy did not show significant results, but it revealed that the cleaning method of samples may have been effective, because the result pointed out no new chemical compounds adsorbed on the surface. To prove that circular economy technique is efficient to the recuperation of ITO thin films, it is suggested the assembly of new OLED devices using the same previous structure of multilayers. This method guarantees that no new variable is included during the assembly process.

The circular economy in OLED devices may be a promising technique for the future of technology, mainly in Brazil, because there is no TCO company in the country. The price of TCOs in the Brazilian market is very expansive and it represents a very expressive cost in OLED devices.

ACKNOWLEDGMENTS

The authors thank the Escola Politécnica of Universidade de São Paulo, Engenharia Metalúrgica e de Materiais, for providing facilities and equipments.

AUTHOR'S CONTRIBUTION

Conceptualization, Data curation, Formal analysis, Funding acquisition, Methodology, Resources, Supervision, Validation, Visualization, Writing – original draft, Writing – review & editing: Santos ER; Conceptualization, Data curation, Formal analysis, Methodology, Visualization, Writing – original draft: Jesus LHS; Conceptualization: Burini Junior; Conceptualization, Funding acquisition, Methodology, Resources, Software: Hui WS; Funding acquisition: Onmori RK; Conceptualization: Hui WS.

FUNDING

Coordenação de Aperfeiçoamento de Pessoal de Nível Superior (CAPES) [http://doi.org/10.13039/501100002322] (PNPD Project N° 02998/09-2).

DATA AVAILABILITY STATEMENT

Data are available in a data repository.

Jesus L H S. Economia Circular em Dispositivos OLEDs [undergraduate thesis]. São Paulo: Faculdade de Tecnologia de São Paulo; 2020.

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